Document Number: MHW8342N Rev. 3, 5/2006

VROHS

Features

- · Specified for up to 132-Channel Loading
- Excellent Distortion Performance
- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

Applications

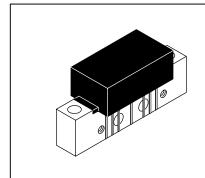
- CATV Systems Operating in the 40 to 870 MHz Frequency Range
- Single Module High Gain Line Amplifier in Cable TV Distribution System

Description

- 24 Vdc Supply, 40 to 870 MHz, CATV High Gain Forward Amplifier Module
- Replaced MHW8342. There are no form, fit or function changes with this part replacement.
- · RoHS Compliant

MHW8342N

870 MHz 35.5 dB GAIN 132-CHANNEL CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V _{in}	+55	dBmV
DC Supply Voltage	V _{CC}	+28	Vdc
Operating Case Temperature Range	T _C	- 20 to +100	°C
Storage Temperature Range	T _{stg}	- 40 to +100	°C

Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted)

Characteris	tic	Symbol	Min	Тур	Max	Unit
Frequency Range		BW	40	_	870	MHz
Power Gain	50 MHz 870 MHz	G _p	33.2 34	34 35.5	34.8 37	dB
Slope	40 - 870 MHz	S	0.5	1.5	2.75	dB
Gain Flatness (Peak To Valley)		G _F	_	0.3	0.8	dB
Return Loss — Input (Z ₀ = 75 Ohms)	40-80 MHz 80-320 MHz 320-640 MHz 640-870 MHz	IRL	22 18 16 14	28 25 22 19	_ _ _ _	dB
Return Loss — Output (Z _o = 75 Ohms)	40-80 MHz 80-240 MHz 240-640 MHz 640-870 MHz	ORL	22 19 17 15	28 25 22 22	_ _ _ _	dB

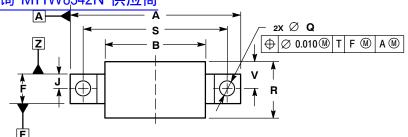
Table 2. Electrical Characteristics (V_{CC} = 24 Vdc, T_{C} = +30°C, 75 Ω system unless otherwise noted) (continued)

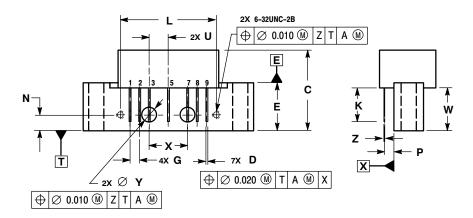
查询"MHW8342N [©] 懊咬蕳 ^{stic}		Symbol	Min	Тур	Max	Unit
Composite Second Order						dBc
(V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CSO ₇₉	_	- 65	- 60	
(V _{out} = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CSO ₁₁₂	_	- 55	- 50	
(V _{out} = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CSO ₁₃₂	_	- 48	- 44	
Cross Modulation Distortion						dBc
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	79-Channel FLAT	XMD ₇₉	_	- 63	- 60	
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	112-Channel FLAT	XMD ₁₁₂	_	- 56	-52	
$(V_{out} = +44 \text{ dBmV}, FM = 55.25 \text{ MHz})$	132-Channel FLAT	XMD ₁₃₂	_	-56	-50	
Composite Triple Beat						dBc
(V _{out} = +44 dBmV/ch., Worst Case)	79-Channel FLAT	CTB ₇₉		- 64	- 62	
(V _{out} = +44 dBmV/ch., Worst Case)	112-Channel FLAT	CTB ₁₁₂	_	- 54	- 51	
(V _{out} = +44 dBmV/ch., Worst Case)	132-Channel FLAT	CTB ₁₃₂	_	-50	- 46	
Noise Figure	50 MHz	NF	=	3.5	4.5	dB
	550 MHz		_	4.5	_	
	870 MHz		_	5.5	6.5	
DC Current		I _{DC}	310	325	350	mA

ARCHIVE INFORMATI

PACKAGE DIMENSIONS

查询"MHW8342N"供应商





CASE 1302-01 ISSUE E

- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
С		0.840		21.336	
D	0.015	0.021	0.381	0.533	
E	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.62	8.255	
G	0.100 BSC		2.540 BSC		
J	0.156	0.156 BSC		BSC	
K	0.315	0.355	8.001	9.017	
L	1.000	BSC	25.400 BSC		
N	0.165 BSC		4.191 BSC		
P	0.100	BSC	2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.24	
S	1.500 BSC		38.100 BSC		
U	0.200 BSC		5.080 BSC		
٧		0.250		6.350	
W	0.435		11.049		
Х	0.400	BSC	10.160 BSC		
Υ	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	

- STYLE 1:
 PIN 1. RF INPUT
 2. GROUND
 3. GROUND
 4. DELETED
 5. VDC
 6. DELETED
 7. GROUND
 8. GROUND
 9. RF OUTPUT

ARCHIVE INFORMATION

查询"MHW8342N"供应商

ARCHIVE INFORMATION

How to Reach Us:

Home Page:

www.freescale.com

E-mail:

support@freescale.com

USA/Europe or Locations Not Listed:

Freescale Semiconductor Technical Information Center, CH370 1300 N. Alma School Road Chandler, Arizona 85224 +1-800-521-6274 or +1-480-768-2130 support@freescale.com

Europe, Middle East, and Africa:

Freescale Halbleiter Deutschland GmbH Technical Information Center Schatzbogen 7 81829 Muenchen, Germany +44 1296 380 456 (English) +46 8 52200080 (English) +49 89 92103 559 (German) +33 1 69 35 48 48 (French) support@freescale.com

Japan:

Freescale Semiconductor Japan Ltd. Headquarters
ARCO Tower 15F
1-8-1, Shimo-Meguro, Meguro-ku, Tokyo 153-0064
Japan
0120 191014 or +81 3 5437 9125
support.japan@freescale.com

Asia/Pacific:

Freescale Semiconductor Hong Kong Ltd.
Technical Information Center
2 Dai King Street
Tai Po Industrial Estate
Tai Po, N.T., Hong Kong
+800 2666 8080
support.asia@freescale.com

For Literature Requests Only:

Freescale Semiconductor Literature Distribution Center P.O. Box 5405
Denver, Colorado 80217
1-800-441-2447 or 303-675-2140
Fax: 303-675-2150
LDCForFreescaleSemiconductor@hibbertgroup.com

Information in this document is provided solely to enable system and software implementers to use Freescale Semiconductor products. There are no express or implied copyright licenses granted hereunder to design or fabricate any integrated circuits or integrated circuits based on the information in this document.

Freescale Semiconductor reserves the right to make changes without further notice to any products herein. Freescale Semiconductor makes no warranty, representation or quarantee regarding the suitability of its products for any particular purpose, nor does Freescale Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters that may be provided in Freescale Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals", must be validated for each customer application by customer's technical experts. Freescale Semiconductor does not convey any license under its patent rights nor the rights of others. Freescale Semiconductor products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Freescale Semiconductor product could create a situation where personal injury or death may occur. Should Buyer purchase or use Freescale Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold Freescale Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Freescale Semiconductor was negligent regarding the design or manufacture of the part.

Freescale [™] and the Freescale logo are trademarks of Freescale Semiconductor, Inc. All other product or service names are the property of their respective owners. © Freescale Semiconductor, Inc. 2006, 2008. All rights reserved.

RoHS-compliant and/or Pb-free versions of Freescale products have the functionality and electrical characteristics of their non-RoHS-compliant and/or non-Pb-free counterparts. For further information, see http://www.freescale.com or contact your Freescale sales representative.

For information on Freescale's Environmental Products program, go to http://www.freescale.com/epp.



Document Number: MHW8342N

Rev. 3, 5/2006